



<u>DDTB (lo-r1) U</u>

PNP PRE-BIASED 500 mA SURFACE MOUNT TRANSISTOR

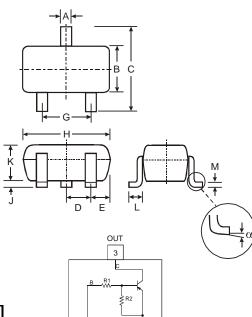
Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTD)
- Built-In Biasing Resistors
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 & 4)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)

P/N	R1 (NOM)	R2 (NOM)	Type Code
DDTB122LU	0.22KΩ	10KΩ	P75
DDTB142JU	0.47KΩ	10KΩ	P76
DDTB122TU	0.22KΩ	OPEN	P77
DDTB142TU	0.47KΩ	OPEN	P78



SOT-323								
Dim	Min	Max						
Α	0.25	0.40						
В	1.15	1.35						
С	2.00	2.20						
D	0.65 N	Iominal						
Е	0.30	0.40						
G	1.20	1.40						
Н	1.80	2.20						
J	0.0	0.10						
Κ	0.90	1.00						
L	0.25	0.40						
М	0.10	0.18						
α	0°	8°						
All Dim	nension	s in mm						

IN GND(+) Schematic and Pin Configuration

2

1

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage, (3) to (2)		V _{CC}	-50	V
Input Voltage, (1) to (2)	DDTB122LU DDTB142JU	V _{IN}	+5 to -6 +5 to -6	V
Input Voltage, (2) to (1)	DDTB122TU DDTB142TU	V _{EBO (MAX)}	-5	V
Output Current	All	Ι _C	-500	mA
Power Dissipation	(Note 1)	Pd	200	mW
Thermal Resistance, Junction to Ambient Air	(Note 1)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range		T_j, T_{STG}	-55 to +150	°C

Notes:

1. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added lead.

3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

 Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



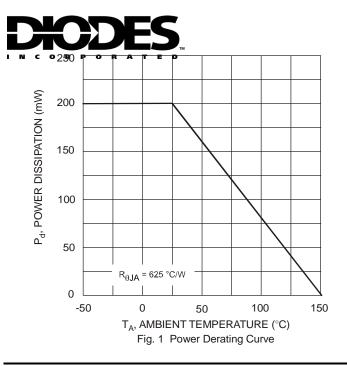
Electrical Characteris	tics @T _A = 25	°C unless other	wise spec	ified	R1, R2 Types			
Characteristi	Symbol Min		Тур	Max	Unit	Test Condition		
Input Voltage	DDTB122LU DDTB142JU	V _{I(off)}	-0.3 -0.3			V	V _{CC} = -5V, I _O = -100µA	
	DDTB122LU DDTB142JU	V _{I(on)}	_	_	-2.0 -2.0		V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -20mA	
Output Voltage		V _{O(on)}	_	_	-0.3V	V	I _O /I _I = -50mA/-2.5mA	
Input Current DDTB122LU DDTB142JU		I			-28 -13	mA	V ₁ = -5V	
Output Current		I _{O(off)}	_	_	-0.5	μΑ	$V_{CC} = -50V, V_I = 0V$	
DC Current Gain DDTB122LU DDTB142JU		GI	56 56			_	V _O = -5V, I _O = -50mA	
Gain-Bandwidth Product*		f⊤	_	200	_	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz	

NEW PRODUCT

* Transistor - For Reference Only

Electrical Characteristic	@T _A = 25°C	unless ot	herwise s	pecified		R1 – Only Types				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition				
Collector-Base Breakdown Voltage		BV _{CBO}	-50		_	V	I _C = -50μA			
Collector-Emitter Breakdown Voltage)	BV _{CEO}	-40		_	V	I _C = -1mA			
Emitter-Base Breakdown Voltage	BV _{EBO}	-5		_	V	I _E = -50μA I _E = -50μA				
Collector Cutoff Current		I _{CBO}	—		-0.5	μA	V _{CB} = -50V			
Emitter Cutoff Current	DDTB122TU DDTB142TU	I _{EBO}			-0.5 -0.5	μA	V _{EB} = -4V			
Collector-Emitter Saturation Voltage		V _{CE(sat)}	—		-0.3	V	I _C = -50mA, I _B = -2.5mA			
DC Current Transfer Ratio	DDTB122TU DDTB142TU	h _{FE}	100 100	250 250	600 600	—	I _C = -5mA, V _{CE} = -5V			
Gain-Bandwidth Product*	•	f _T	—	200	—	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz			

* Transistor - For Reference Only

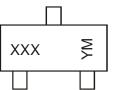


Ordering Information (Note 4 & 5)

Device	Packaging	Shipping
DDTB122LU-7-F	SOT-323	3000/Tape & Reel
DDTB142JU-7-F	SOT-323	3000/Tape & Reel
DDTB122TU-7-F	SOT-323	3000/Tape & Reel
DDTB142TU-7-F	SOT-323	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



 $\begin{array}{l} XXX = \mbox{Product Type Marking Code} \ \ (\mbox{See Page 1}) \\ YM = \mbox{Date Code Marking} \\ Y = \mbox{Year ex: } T = 2006 \\ M = \mbox{Month ex: } 9 = \mbox{September} \end{array}$

Date Code Key							
Year	2006	2007	2008	2009	2010	2011	2012
Code	Т	U	V	W	Х	Y	Z
							1

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Νον	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D

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